



AF Amp Applications

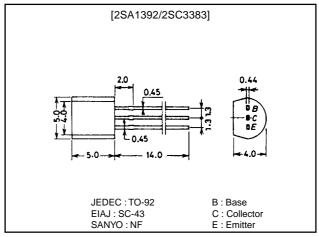
Features

- · Adoption of FBET process.
- · AF amp.

Package Dimensions

unit:mm

2003A



(): 2SA1392

Specifications

Absolute Maximum Ratings at Ta = 25°C

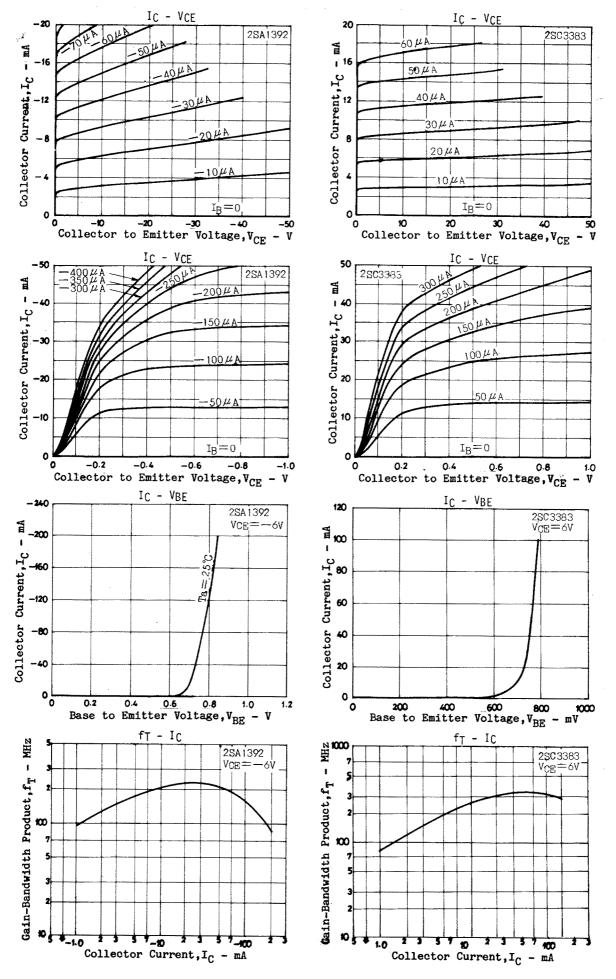
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		(–)60	V
Collector-to-Emitter Voltage	V _{CEO}		(–)50	V
Emitter-to-Base Voltage	V _{EBO}		(–)6	V
Collector Current	IC		(-)200	mA
Collector Current (Pulse)	I _{CP}		(-)400	mA
Collector Dissipation	PC		400	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

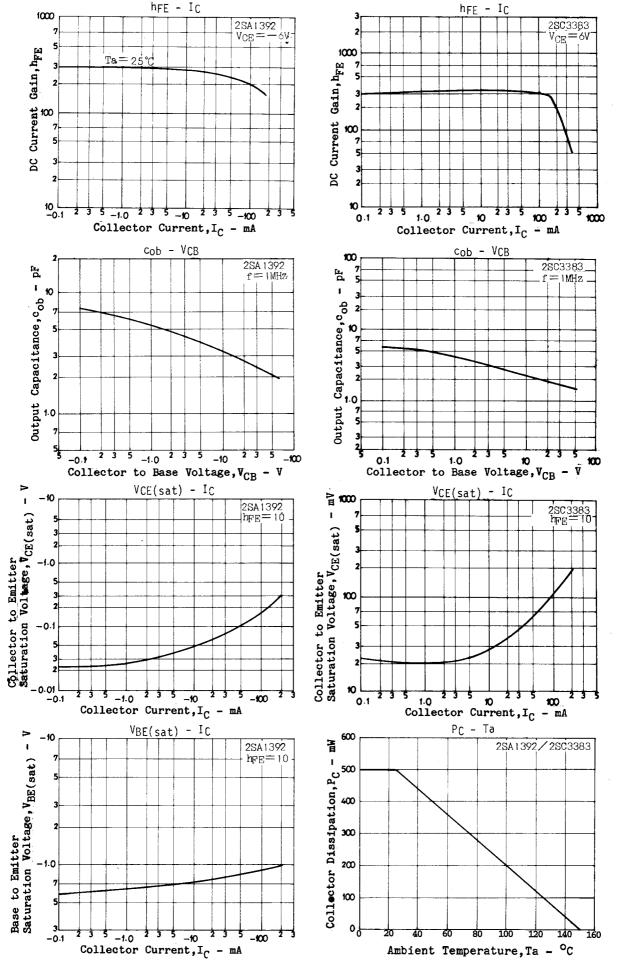
Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		I India		
Parameter	Symbol	Conditions	min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =(-)40V, I _E =0			(–)0.1	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB=} (-)5V, I _C =0			(-)0.1	μΑ
DC Current Gain	h _{FE} 1	V _{CE} =(-)6V, I _C =(-)1mA	100*		560*	
	h _{FE} 2	V _{CE} =(-)6V, I _C =(-)0.1mA	70			
Gain-Bandwidth Product	f _T	V _{CE} =(-)6V, I _C =(-)10mA		250		MHz
				(200)		MHz
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =(-)100mA, I _B =(-)10mA			(-)0.3	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =(-)100mA, I _B =(-)10mA			(-)1.0	V
Output Capacitance	C _{ob}	V _{CB} =(-)6V, f=1MHz		2.7		pF
				(3.7)		pF
Collector-to-Base Breakdown Voltage	V _(BR) CBO	I _C =(-)10μΑ, I _E =0	(–)60			V
Collector-to-Emitter Breakdown Voltage	V _(BR) CEO	I _C =(-)1mA, R _{BE} =∞	(–)50			V
Emitter-to-Base Breakdown Votage	V _{(BR)EBO}	I _E =(-)10μΑ, I _C =0	(–)6			V

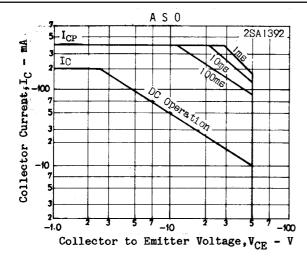
^{* :} The 2SA1392/2SC3383 are classified by 1mA h_{FE} as follows :

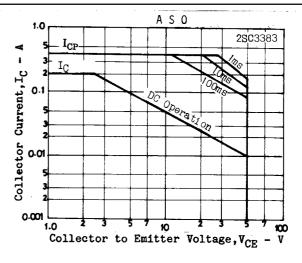
100	R	200	140	S	280	200	Т	400	280	U	560
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2SA1392/2SC3383





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